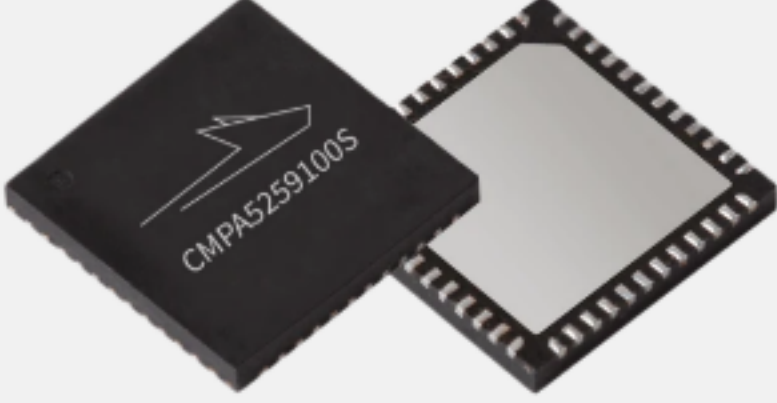


# CMPA5259100








## 5.0 - 5.9 GHz, 100W GaN MMIC HPA

Wolfspeed’s CMPA5259100S is a 100W package MMIC HPA utilizing Wolfspeed’s high performance, 50V GaN on SiC production process. The CMPA5259100S operates from 5.0-5.9 GHz and supports both defense and commercial-related radar applications. The CMPA5259100S achieves 100W of saturated output power with 25 dB of large signal gain and very high power-added efficiency under pulsed operation.

## Products

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Product SKU	Buy Online	Request Sample	Data Sheet	Recommended For New Design?	Technology	Frequency Min	Frequency Max	Peak Output Power
CMPA5259100S-AMP1	<div>NEW</div> <div></div>	<div></div> <div>Request Now</div>		Yes	GaN on SiC	5 GHz	5.9 GHz	100 W
CMPA5259100S	<div>NEW</div> <div></div>	<div></div> <div>Request Now</div>		Yes	GaN on SiC	5 GHz	5.9 GHz	100 W













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Applications
  - Pulsed Military and Commercial Radar


Technical & Sales Documents	Tools & Support
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Document Type

+


Document Type	Document Name
Application Notes	<div> Eutectic Die Attach Procedure</div>
Application Notes	<div> GaN HEMT Bias Sequencing and Temperature Compensation Circuit</div>
Design Files	<div> CMPA5259100S-AMP1 All Design Files</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 50 V – IDQ = 100 mA – 85 C</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 40V – IDQ = 100 mA – 25 C</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 45V – IDQ = 100 mA – 25 C</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 50V – IDQ = 100 mA – 25 C</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 50V – IDQ = 100 mA – -40 C</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 50V – IDQ = 200 mA – 25 C</div>
S-parameters	<div> CMPA5259100S S-parameters – VDS = 50V – IDQ = 50 mA – 25 C</div>
Product Catalog	<div> RF Aerospace &amp; Defense Line Card</div>
Sales Terms	<div> Wolfspeed, Inc. Sales Terms and Conditions</div>

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